

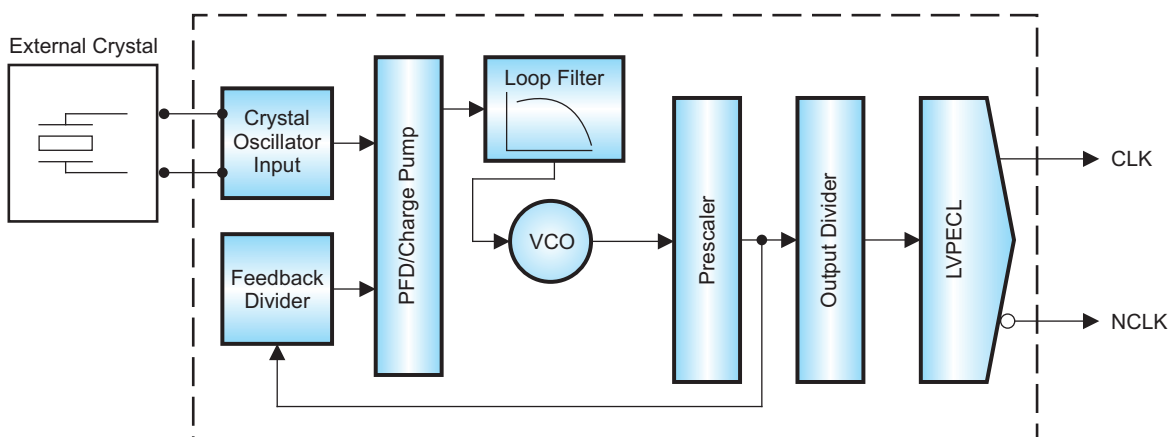
## FULLY INTEGRATED FIXED FREQUENCY LOW-JITTER, CRYSTAL-OSCILLATOR CLOCK GENERATOR

### FEATURES

- Single 3.3 V Supply
- High-Performance Clock Generator, Incorporating Crystal Oscillator Circuitry With Integrated Frequency Synthesizer
- Low Output Jitter, as Low as 380 fs (rms integrated between 10 kHz–20 MHz)
- Low Phase Noise at 312.5 MHz, Less Than –120 dBc/Hz at 10 kHz and –147 dBc/Hz at 10 MHz Offset From the Carrier
- Supports Crystal Frequencies or LVCMOS Input Frequencies at 31.25 MHz, 33.33 MHz, and 35.42 MHz
- Output Frequencies: 100 MHz, 106.25 MHz, 125 MHz, 156.25 MHz, 212.5 MHz, 250 MHz, and 312.5 MHz
- Differential Low-Voltage Positive Emitter Coupled Logic (LVPECL) Output
- Fully Integrated Voltage-Controlled Oscillator (VCO) Running from 1.75 GHz to 2.35 GHz
- Typical Power Consumption 300 mW
- Chip-Enable Control Pin
- QFN-24 Package
- ESD Protection Exceeds 2 kV HBM
- Industrial Temperature Range –40°C to 85°C

### APPLICATIONS

- Low-Cost, Low-Jitter Frequency Multiplier



B0216-02

### DESCRIPTION

CDC421xxx is a high-performance, low-phase-noise clock generator. It has an integrated low-noise, LC-based voltage-controlled oscillator (VCO) that operates within the 1.75 GHz–2.35 GHz frequency range. It has an integrated crystal oscillator that operates in conjunction with an external AT-cut crystal to produce a stable frequency reference for the PLL-based frequency synthesizer. The output frequency ( $f_{out}$ ) is proportional to the frequency of the input crystal ( $f_{xtal}$ ).

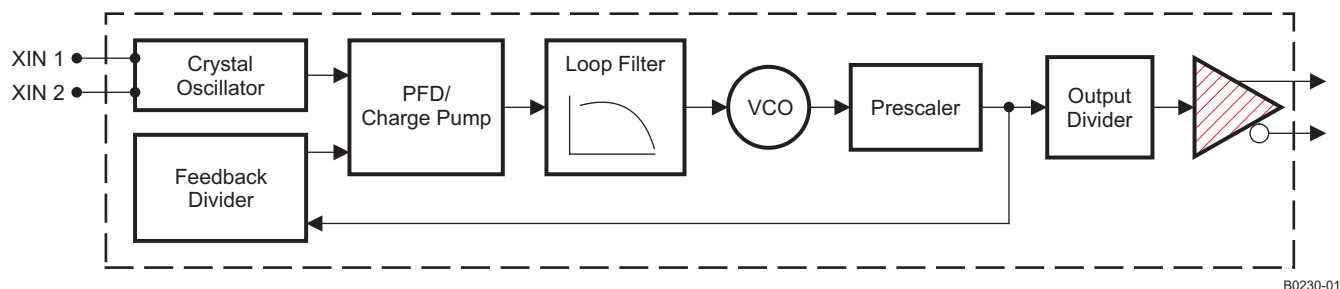
The device operates in a 3.3 V supply environment and is characterized for operation from –40°C to 85°C.

CDC421xxx is available in a QFN-24 package.

A high-level block diagram of the CDC421xxx is shown in [Figure 1](#).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

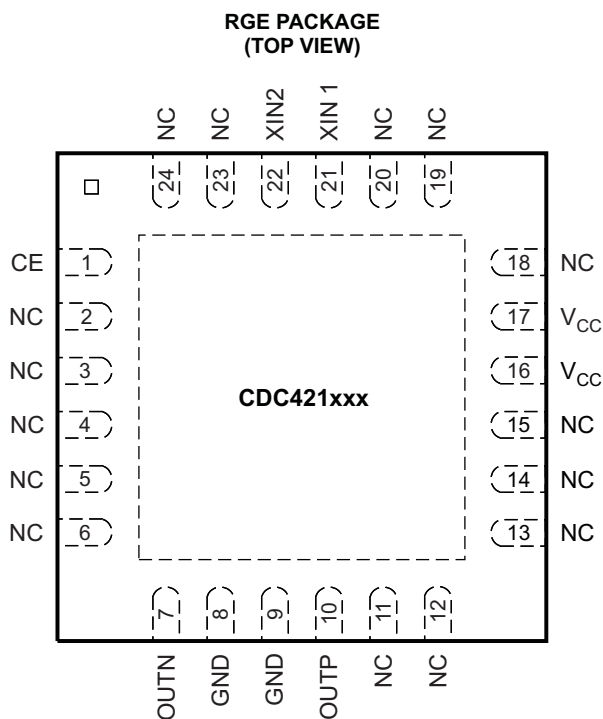


B0230-01

**Figure 1. High-Level Block Diagram of the CDC421xxx**

## PACKAGE (QFN-24)

The CDC421xxx is packaged in a QFN-24 terminal package. The QFN package footprint is shown. Terminal locations and numbers are shown in [Figure 2](#).



P0024-06

**Figure 2. Pinout of the CDC421xxx QFN-24 Package**

The terminal functions table shows the terminal descriptions for the CDC421xxx QFN-24 package.

**Table 1. TERMINAL FUNCTIONS**

| TERMINAL        |        | TYPE  | ESD PROTECTION | DESCRIPTION                                                                                                                                                                                                       |
|-----------------|--------|-------|----------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME            | NO.    |       |                |                                                                                                                                                                                                                   |
| V <sub>CC</sub> | 16, 17 | Power | Y              | 3.3V power supply                                                                                                                                                                                                 |
| GND             | 8, 9   | GND   | Y              | Ground                                                                                                                                                                                                            |
| XIN 1           | 21     | I     | Y              | In crystal input mode, connect XIN1 to one end of the crystal and XIN2 to the other end of the crystal. In LVCMOS single-ended driven mode, XIN1 (pin 21) acts as input reference and XIN2 should connect to GND. |
| XIN 2           | 22     | I     | N              |                                                                                                                                                                                                                   |

**Table 1. TERMINAL FUNCTIONS (continued)**

| TERMINAL |                                 | TYPE   | ESD PROTECTION | DESCRIPTION                                                                                                                                 |
|----------|---------------------------------|--------|----------------|---------------------------------------------------------------------------------------------------------------------------------------------|
| NAME     | NO.                             |        |                |                                                                                                                                             |
| CE       | 1                               | I      | Y              | Chip enable (LVCMOS input)<br>CE = 1 enables the device and the outputs.<br>CE = 0 disables all current sources (LVPECLP = LVPECLN = Hi-Z). |
| OUTP     | 10                              | O      | Y              | High-speed positive differential LVPECL output. (Outputs are enabled by CE )                                                                |
| OUTN     | 7                               | O      | Y              | High-speed negative differential LVPECL output. (Outputs are enabled by CE )                                                                |
| NC       | 2–6, 11–15,<br>18–20, 23,<br>24 | I or O | Y              | TI test pin. Do not connect; leave floating.                                                                                                |

## DEVICE SELECTION

The CDC421xxx device is an LVPECL low-phase-noise clock generator designed to work with a low-frequency AT-crystal oscillator of a single-ended LVCMOS.

**Table 2. Device Selection Table for CDC421xxx**

| CDC421xxx      |                      | PACKAGE                    | INPUT FREQUENCY OR CRYSTAL VALUE (MHz) | OUTPUT FREQUENCY FOR THE SPECIFIED INPUT FREQUENCY (MHz) |
|----------------|----------------------|----------------------------|----------------------------------------|----------------------------------------------------------|
| DEVICE MARKING | ORDERING PART NUMBER |                            |                                        |                                                          |
| 421100         | CDC421100RGER        | QFN-24 tape and reel       | 33.3333                                | 100.00                                                   |
| 421100         | CDC421100RGET        | QFN-24 small tape and reel | 33.3333                                | 100.00                                                   |
| 421106         | CDC421106RGER        | QFN-24 tape and reel       | 35.4167                                | 106.25                                                   |
| 421106         | CDC421106RGET        | QFN-24 small tape and reel | 35.4167                                | 106.25                                                   |
| 421125         | CDC421125RGER        | QFN-24 tape and reel       | 31.2500                                | 125.00                                                   |
| 421125         | CDC421125RGET        | QFN-24 small tape and reel | 31.2500                                | 125.00                                                   |
| 421156         | CDC421156RGER        | QFN-24 tape and reel       | 31.2500                                | 156.25                                                   |
| 421156         | CDC421156RGET        | QFN-24 small tape and reel | 31.2500                                | 156.25                                                   |
| 421212         | CDC421212RGER        | QFN-24 tape and reel       | 35.4167                                | 212.50                                                   |
| 421212         | CDC421212RGET        | QFN-24 small tape and reel | 35.4167                                | 212.50                                                   |
| 421250         | CDC421250RGER        | QFN-24 tape and reel       | 31.2500                                | 250.00                                                   |
| 421250         | CDC421250RGET        | QFN-24 small tape and reel | 31.2500                                | 250.00                                                   |
| 421312         | CDC421312RGER        | QFN-24 tape and reel       | 31.2500                                | 312.50                                                   |
| 421312         | CDC421312RGET        | QFN-24 small tape and reel | 31.2500                                | 312.50                                                   |

## ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

|                                                                      | VALUE                         | UNIT |
|----------------------------------------------------------------------|-------------------------------|------|
| V <sub>CC</sub> Supply voltage <sup>(2)</sup>                        | –0.5 to 4.6                   | V    |
| V <sub>I</sub> Voltage range for all other input pins <sup>(2)</sup> | –0.5 to V <sub>CC</sub> + 0.5 | V    |
| I <sub>O</sub> Output current for LVPECL                             | –50                           | mA   |
| Electrostatic discharge (HBM)                                        | 2 k                           | V    |
| T <sub>A</sub> Characterized free-air temperature range (no airflow) | –40 to 85                     | °C   |
| T <sub>J</sub> Maximum junction temperature                          | 125                           | °C   |
| T <sub>stg</sub> Storage temperature range                           | –65 to 150                    | °C   |

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to network ground terminal.

## RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

|          |                                               | MIN | NOM | MAX | UNIT |
|----------|-----------------------------------------------|-----|-----|-----|------|
| $V_{CC}$ | Supply voltage                                | 3   | 3.3 | 3.6 | V    |
| $T_A$    | Ambient temperature, no airflow, no heat sink | –40 |     | 85  | °C   |

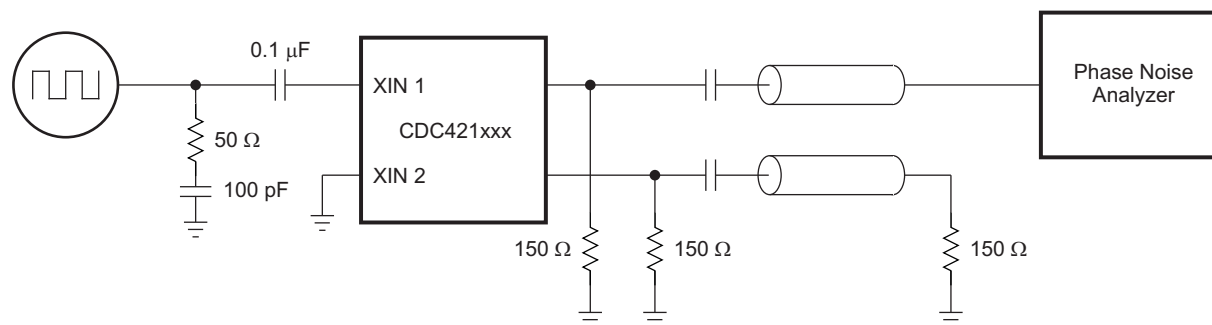
## ELECTRICAL CHARACTERISTICS

over recommended operating conditions for CDC421xxx device

| PARAMETER            | TEST CONDITIONS                    | MIN                                                 | TYP          | MAX             | UNIT |
|----------------------|------------------------------------|-----------------------------------------------------|--------------|-----------------|------|
| $V_{CC}$             | Supply voltage                     | 3                                                   | 3.3          | 3.6             | V    |
| $I_{VCC}$            | Total current at 3.3 V             | 3.3 V, 312.5 MHz                                    | 91           | 110             | mA   |
| <b>LVPECL OUTPUT</b> |                                    |                                                     |              |                 |      |
| $f_{CLK}$            | Output frequency                   |                                                     | 100          | 312.5           | MHz  |
| $V_{OH}$             | LVPECL high-level output voltage   | $V_{CC} - 1.20$                                     |              | $V_{CC} - 0.81$ | V    |
| $V_{OL}$             | LVPECL low-level output voltage    | $V_{CC} - 2.17$                                     |              | $V_{CC} - 1.36$ | V    |
| $ V_{OD} $           | LVPECL differential output voltage | 407                                                 |              | 1076            | mV   |
| $t_r$                | Output rise time                   | 20% to 80% of $V_{OUTpp}$                           | 170          |                 | ps   |
| $t_f$                | Output fall time                   | 80% to 20% of $V_{OUTpp}$                           | 170          |                 | ps   |
|                      | Duty cycle of the output waveform  | 45%                                                 |              | 55%             |      |
| <b>LVCMOS INPUT</b>  |                                    |                                                     |              |                 |      |
| $V_{IL,CMOS}$        | Low-level CMOS input voltage       | $V_{CC} = 3.3\text{ V}$                             |              | $0.3 V_{CC}$    | V    |
| $V_{IH,CMOS}$        | High-level CMOS input voltage      | $V_{CC} = 3.3\text{ V}$                             | $0.7 V_{CC}$ |                 | V    |
| $I_{L,CMOS}$         | Low-level CMOS input current       | $V_{CC} = V_{CC\text{ max}}, V_{IL} = 0\text{ V}$   |              | –200            | μA   |
| $I_{H,CMOS}$         | High-level CMOS input current      | $V_{CC} = V_{CC\text{ min}}, V_{IH} = 3.7\text{ V}$ |              | 200             | μA   |

## JITTER CHARACTERISTICS IN INPUT CLOCK MODE

The jitter characterization test is performed using an LVCMOS input signal driving the CDC421xxx device.



S0246-02

**Figure 3. Jitter Test Configuration for an LVTTTL Input Driving CDC421xxx**

For the cases of the CDC421xxx being referenced by an external, clean LVCMOS input of 31.25 MHz, 33.33 MHz and 35.4167 MHz, the following tables list the measured SSB phase noise of all the outputs supported by the CDC421xxx device, (100 MHz, 106.25 MHz, 125 MHz, 156.25 MHz, 212.5 MHz, 250 MHz, and 312.5 MHz) from 100 Hz to 20 MHz from the carrier.

**Table 3. Phase Noise Parameters With LVCMOS Input of 33.3333 MHz and LVPECL Output at 100.00 MHz**

| PARAMETER                                                                                                                          |                                             | MIN | TYP   | MAX | UNIT   |
|------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------|-----|-------|-----|--------|
| <b>Phase Noise Specifications Under Following Conditions: <math>f_{in} = 33.3333</math> MHz, <math>f_{out} = 100.00</math> MHz</b> |                                             |     |       |     |        |
| phn <sub>100</sub>                                                                                                                 | Phase noise at 100 Hz                       |     | -111  |     | dBc/Hz |
| phn <sub>1K</sub>                                                                                                                  | Phase noise at 1 kHz                        |     | -121  |     | dBc/Hz |
| phn <sub>10k</sub>                                                                                                                 | Phase noise at 10 kHz                       |     | -131  |     | dBc/Hz |
| phn <sub>100k</sub>                                                                                                                | Phase noise at 100 kHz                      |     | -133  |     | dBc/Hz |
| phn <sub>1M</sub>                                                                                                                  | Phase noise at 1 MHz                        |     | -142  |     | dBc/Hz |
| phn <sub>10M</sub>                                                                                                                 | Phase noise at 10 MHz                       |     | -149  |     | dBc/Hz |
| phn <sub>20M</sub>                                                                                                                 | Phase noise at 20 MHz                       |     | -149  |     | dBc/Hz |
| J <sub>RMS</sub>                                                                                                                   | RMS jitter integrated from 12 kHz to 20 MHz |     | 507   |     | fs     |
| Tj                                                                                                                                 | Total jitter                                |     | 35.33 |     | ps     |
| Dj                                                                                                                                 | Deterministic jitter                        |     | 11.54 |     | ps     |

**Table 4. Phase Noise Parameters With LVCMOS Input of 35.4167 MHz and LVPECL Output at 106.25 MHz**

| PARAMETER                                                                                                                          |                                             | MIN | TYP   | MAX | UNIT   |
|------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------|-----|-------|-----|--------|
| <b>Phase Noise Specifications Under Following Conditions: <math>f_{in} = 35.4167</math> MHz, <math>f_{out} = 106.25</math> MHz</b> |                                             |     |       |     |        |
| phn <sub>100</sub>                                                                                                                 | Phase noise at 100 Hz                       |     | -112  |     | dBc/Hz |
| phn <sub>1K</sub>                                                                                                                  | Phase noise at 1 kHz                        |     | -121  |     | dBc/Hz |
| phn <sub>10k</sub>                                                                                                                 | Phase noise at 10 kHz                       |     | -125  |     | dBc/Hz |
| phn <sub>100k</sub>                                                                                                                | Phase noise at 100 kHz                      |     | -129  |     | dBc/Hz |
| phn <sub>1M</sub>                                                                                                                  | Phase noise at 1 MHz                        |     | -142  |     | dBc/Hz |
| phn <sub>10M</sub>                                                                                                                 | Phase noise at 10 MHz                       |     | -151  |     | dBc/Hz |
| phn <sub>20M</sub>                                                                                                                 | Phase noise at 20 MHz                       |     | -151  |     | dBc/Hz |
| J <sub>RMS</sub>                                                                                                                   | RMS jitter integrated from 12 kHz to 20 MHz |     | 530   |     | fs     |
| Tj                                                                                                                                 | Total jitter                                |     | 30.39 |     | ps     |
| Dj                                                                                                                                 | Deterministic jitter                        |     | 11    |     | ps     |

**Table 5. Phase Noise Parameters With LVCMOS Input of 31.2500 MHz and LVPECL Output at 125.00 MHz**

| PARAMETER                                                                                                                          |                                             | MIN | TYP   | MAX | UNIT   |
|------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------|-----|-------|-----|--------|
| <b>Phase Noise Specifications Under Following Conditions: <math>f_{in} = 31.2500</math> MHz, <math>f_{out} = 125.00</math> MHz</b> |                                             |     |       |     |        |
| phn <sub>100</sub>                                                                                                                 | Phase noise at 100 Hz                       |     | -108  |     | dBc/Hz |
| phn <sub>1K</sub>                                                                                                                  | Phase noise at 1 kHz                        |     | -118  |     | dBc/Hz |
| phn <sub>10k</sub>                                                                                                                 | Phase noise at 10 kHz                       |     | -127  |     | dBc/Hz |
| phn <sub>100k</sub>                                                                                                                | Phase noise at 100 kHz                      |     | -130  |     | dBc/Hz |
| phn <sub>1M</sub>                                                                                                                  | Phase noise at 1 MHz                        |     | -139  |     | dBc/Hz |
| phn <sub>10M</sub>                                                                                                                 | Phase noise at 10 MHz                       |     | -147  |     | dBc/Hz |
| phn <sub>20M</sub>                                                                                                                 | Phase noise at 20 MHz                       |     | -147  |     | dBc/Hz |
| J <sub>RMS</sub>                                                                                                                   | RMS jitter integrated from 12 kHz to 20 MHz |     | 529   |     | fs     |
| T <sub>j</sub>                                                                                                                     | Total jitter                                |     | 47.47 |     | ps     |
| D <sub>j</sub>                                                                                                                     | Deterministic jitter                        |     | 25.2  |     | ps     |

**Table 6. Phase Noise Parameters With LVCMOS Input of 31.2500 MHz and LVPECL Output at 156.25 MHz**

| PARAMETER                                                                                                                          |                                             | MIN | TYP   | MAX | UNIT   |
|------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------|-----|-------|-----|--------|
| <b>Phase Noise Specifications Under Following Conditions: <math>f_{in} = 31.2500</math> MHz, <math>f_{out} = 156.25</math> MHz</b> |                                             |     |       |     |        |
| phn <sub>100</sub>                                                                                                                 | Phase noise at 100 Hz                       |     | -106  |     | dBc/Hz |
| phn <sub>1K</sub>                                                                                                                  | Phase noise at 1 kHz                        |     | -117  |     | dBc/Hz |
| phn <sub>10k</sub>                                                                                                                 | Phase noise at 10 kHz                       |     | -126  |     | dBc/Hz |
| phn <sub>100k</sub>                                                                                                                | Phase noise at 100 kHz                      |     | -128  |     | dBc/Hz |
| phn <sub>1M</sub>                                                                                                                  | Phase noise at 1 MHz                        |     | -139  |     | dBc/Hz |
| phn <sub>10M</sub>                                                                                                                 | Phase noise at 10 MHz                       |     | -147  |     | dBc/Hz |
| phn <sub>20M</sub>                                                                                                                 | Phase noise at 20 MHz                       |     | -147  |     | dBc/Hz |
| J <sub>RMS</sub>                                                                                                                   | RMS jitter integrated from 12 kHz to 20 MHz |     | 472   |     | fs     |
| T <sub>j</sub>                                                                                                                     | Total jitter                                |     | 31.54 |     | ps     |
| D <sub>j</sub>                                                                                                                     | Deterministic jitter                        |     | 9.12  |     | ps     |

**Table 7. Phase Noise Parameters With LVCMOS Input of 35.4167 MHz and LVPECL Output at 212.50 MHz**

| PARAMETER                                                                                                                          |                                             | MIN | TYP   | MAX | UNIT   |
|------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------|-----|-------|-----|--------|
| <b>Phase Noise Specifications Under Following Conditions: <math>f_{in} = 35.4167</math> MHz, <math>f_{out} = 212.50</math> MHz</b> |                                             |     |       |     |        |
| phn <sub>100</sub>                                                                                                                 | Phase noise at 100 Hz                       |     | -105  |     | dBc/Hz |
| phn <sub>1K</sub>                                                                                                                  | Phase noise at 1 kHz                        |     | -115  |     | dBc/Hz |
| phn <sub>10k</sub>                                                                                                                 | Phase noise at 10 kHz                       |     | -119  |     | dBc/Hz |
| phn <sub>100k</sub>                                                                                                                | Phase noise at 100 kHz                      |     | -123  |     | dBc/Hz |
| phn <sub>1M</sub>                                                                                                                  | Phase noise at 1 MHz                        |     | -135  |     | dBc/Hz |
| phn <sub>10M</sub>                                                                                                                 | Phase noise at 10 MHz                       |     | -148  |     | dBc/Hz |
| phn <sub>20M</sub>                                                                                                                 | Phase noise at 20 MHz                       |     | -148  |     | dBc/Hz |
| J <sub>RMS</sub>                                                                                                                   | RMS jitter integrated from 12 kHz to 20 MHz |     | 512   |     | fs     |
| T <sub>j</sub>                                                                                                                     | Total jitter                                |     | 33.96 |     | ps     |
| D <sub>j</sub>                                                                                                                     | Deterministic jitter                        |     | 13.78 |     | ps     |

**Table 8. Phase Noise Parameters With LVCMOS Input of 31.2500 MHz and LVPECL Output at 250.00 MHz**

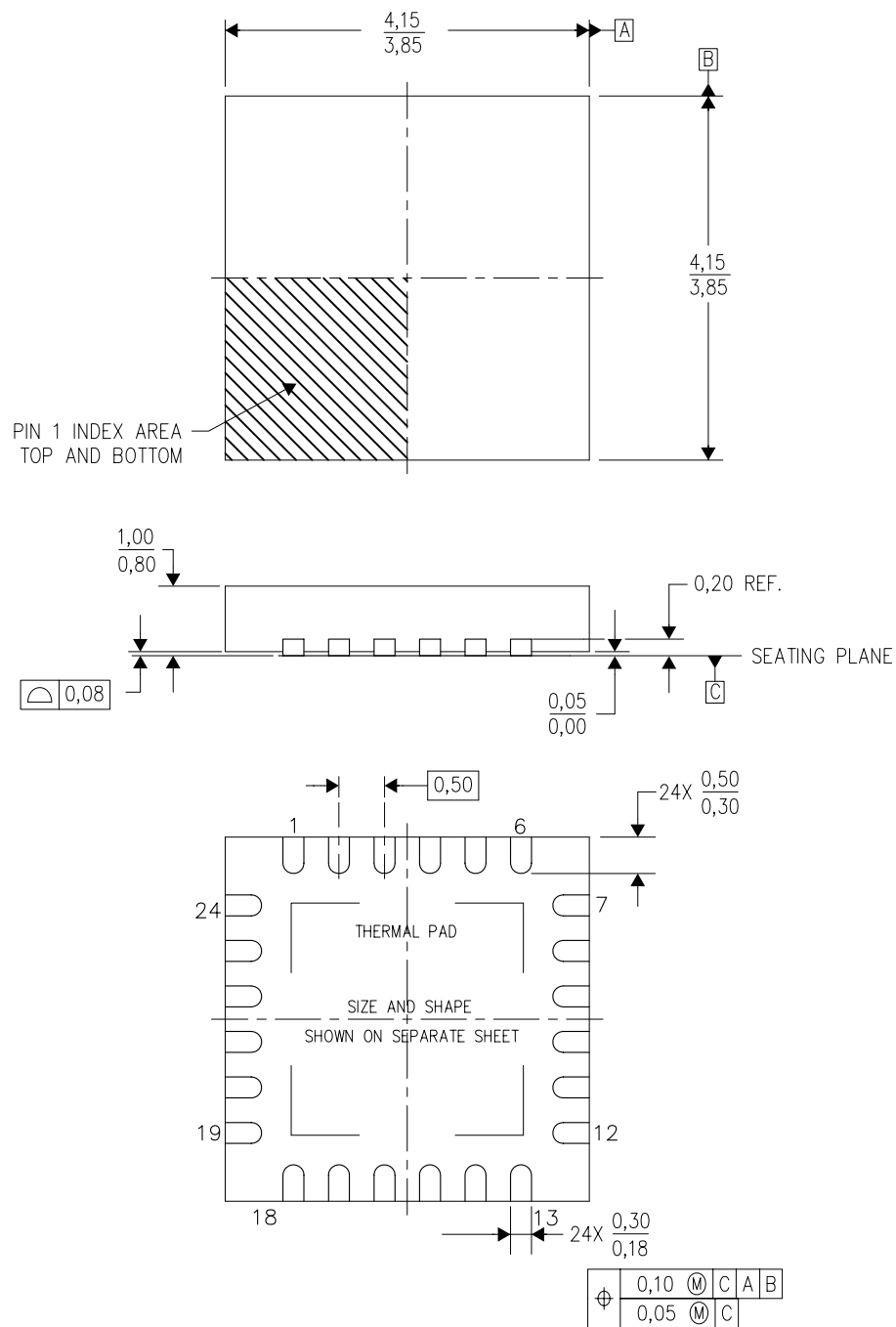
| PARAMETER                                                                                                                          |                                             | MIN | TYP   | MAX | UNIT   |
|------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------|-----|-------|-----|--------|
| <b>Phase Noise Specifications Under Following Conditions: <math>f_{in} = 31.2500</math> MHz, <math>f_{out} = 250.00</math> MHz</b> |                                             |     |       |     |        |
| phn <sub>100</sub>                                                                                                                 | Phase noise at 100 Hz                       |     | –103  |     | dBc/Hz |
| phn <sub>1K</sub>                                                                                                                  | Phase noise at 1 kHz                        |     | –112  |     | dBc/Hz |
| phn <sub>10k</sub>                                                                                                                 | Phase noise at 10 kHz                       |     | –121  |     | dBc/Hz |
| phn <sub>100k</sub>                                                                                                                | Phase noise at 100 kHz                      |     | –124  |     | dBc/Hz |
| phn <sub>1M</sub>                                                                                                                  | Phase noise at 1 MHz                        |     | –134  |     | dBc/Hz |
| phn <sub>10M</sub>                                                                                                                 | Phase noise at 10 MHz                       |     | –148  |     | dBc/Hz |
| phn <sub>20M</sub>                                                                                                                 | Phase noise at 20 MHz                       |     | –149  |     | dBc/Hz |
| J <sub>RMS</sub>                                                                                                                   | RMS jitter integrated from 12 kHz to 20 MHz |     | 420   |     | fs     |
| T <sub>j</sub>                                                                                                                     | Total jitter                                |     | 36.98 |     | ps     |
| D <sub>j</sub>                                                                                                                     | Deterministic jitter                        |     | 18.52 |     | ps     |

**Table 9. Phase Noise Parameters With LVCMOS Input of 31.2500 MHz and LVPECL Output at 312.50 MHz**

| PARAMETER                                                                                                                          |                                             | MIN | TYP   | MAX | UNIT   |
|------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------|-----|-------|-----|--------|
| <b>Phase Noise Specifications Under Following Conditions: <math>f_{in} = 31.2500</math> MHz, <math>f_{out} = 312.50</math> MHz</b> |                                             |     |       |     |        |
| phn <sub>100</sub>                                                                                                                 | Phase noise at 100 Hz                       |     | –102  |     | dBc/Hz |
| phn <sub>1K</sub>                                                                                                                  | Phase noise at 1 kHz                        |     | –111  |     | dBc/Hz |
| phn <sub>10k</sub>                                                                                                                 | Phase noise at 10 kHz                       |     | –120  |     | dBc/Hz |
| phn <sub>100k</sub>                                                                                                                | Phase noise at 100 kHz                      |     | –123  |     | dBc/Hz |
| phn <sub>1M</sub>                                                                                                                  | Phase noise at 1 MHz                        |     | –135  |     | dBc/Hz |
| phn <sub>10M</sub>                                                                                                                 | Phase noise at 10 MHz                       |     | –147  |     | dBc/Hz |
| phn <sub>20M</sub>                                                                                                                 | Phase noise at 20 MHz                       |     | –147  |     | dBc/Hz |
| J <sub>RMS</sub>                                                                                                                   | RMS jitter integrated from 12 kHz to 20 MHz |     | 378   |     | fs     |
| T <sub>j</sub>                                                                                                                     | Total jitter                                |     | 29.82 |     | ps     |
| D <sub>j</sub>                                                                                                                     | Deterministic jitter                        |     | 11    |     | ps     |

RGE (S-PVQFN-N24)

PLASTIC QUAD FLATPACK NO-LEAD



4204104/G 07/11

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. Quad Flatpack, No-Leads (QFN) package configuration.
  - D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
  - E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
  - F. Falls within JEDEC MO-220.

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Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

### Products

|                              |                                                                                      |
|------------------------------|--------------------------------------------------------------------------------------|
| Audio                        | <a href="http://www.ti.com/audio">www.ti.com/audio</a>                               |
| Amplifiers                   | <a href="http://amplifier.ti.com">amplifier.ti.com</a>                               |
| Data Converters              | <a href="http://dataconverter.ti.com">dataconverter.ti.com</a>                       |
| DLP® Products                | <a href="http://www.dlp.com">www.dlp.com</a>                                         |
| DSP                          | <a href="http://dsp.ti.com">dsp.ti.com</a>                                           |
| Clocks and Timers            | <a href="http://www.ti.com/clocks">www.ti.com/clocks</a>                             |
| Interface                    | <a href="http://interface.ti.com">interface.ti.com</a>                               |
| Logic                        | <a href="http://logic.ti.com">logic.ti.com</a>                                       |
| Power Mgmt                   | <a href="http://power.ti.com">power.ti.com</a>                                       |
| Microcontrollers             | <a href="http://microcontroller.ti.com">microcontroller.ti.com</a>                   |
| RFID                         | <a href="http://www.ti-rfid.com">www.ti-rfid.com</a>                                 |
| OMAP Applications Processors | <a href="http://www.ti.com/omap">www.ti.com/omap</a>                                 |
| Wireless Connectivity        | <a href="http://www.ti.com/wirelessconnectivity">www.ti.com/wirelessconnectivity</a> |

### Applications

|                               |                                                                                          |
|-------------------------------|------------------------------------------------------------------------------------------|
| Automotive and Transportation | <a href="http://www.ti.com/automotive">www.ti.com/automotive</a>                         |
| Communications and Telecom    | <a href="http://www.ti.com/communications">www.ti.com/communications</a>                 |
| Computers and Peripherals     | <a href="http://www.ti.com/computers">www.ti.com/computers</a>                           |
| Consumer Electronics          | <a href="http://www.ti.com/consumer-apps">www.ti.com/consumer-apps</a>                   |
| Energy and Lighting           | <a href="http://www.ti.com/energy">www.ti.com/energy</a>                                 |
| Industrial                    | <a href="http://www.ti.com/industrial">www.ti.com/industrial</a>                         |
| Medical                       | <a href="http://www.ti.com/medical">www.ti.com/medical</a>                               |
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